

# **PN4117A**

### **N-Channel Switch**

- This device is designed for low current DC and audio application. These devices provide excellent performance as input stages for subpicoamp instrumentation or any high impedance signal sources.
- Sourced from process 53.



1. Drain 2. Source 3. Gate

# **Absolute Maximum Ratings \*** T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	40	V
$V_{GS}$	Gate-Source Voltage	-40	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>STG</sub>	Operating and storage Temperature Range	- 55 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired

- These ratings are based on a maximum junction temperature of 150degrees C.
  These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

## Electrical Characteristics T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics		•	•	•	•
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_{G} = -1\mu A$	-40			V
V <sub>GS</sub> (off)	Gate-Source Cutoff Voltage	$V_{DS} = -10V, I_{D} = 1.0nA$	-0.6		-1.8	V
I <sub>GSS</sub>	Gate Reverse Current	$V_{DS} = 0V, V_{GS} = -20V$			-1.0	pА
On Chara	cteristics		•	•	•	•
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current *	$V_{DS} = 10V, V_{GS} = 0$	30		90	μΑ
Small Sig	nal Characteristics		•		•	•
gfs	Common Source Forward Transconductance	$V_{DS} = 10V, V_{GS} = 0$ f = 1.0KHz	70		210	mmhos
g <sub>oss</sub>	Common Source Output Conductance	$V_{DS} = 10V, V_{GS} = 0$ f = 1KHz			3.0	mmhos
R <sub>E(YFS)</sub>	Common Source Forward Conductance	$V_{DS} = 10V, V_{GS} = 0$ f = 30MHz	60			mmhos
C <sub>ISS</sub>	Input Capacitance	$V_{DS} = 10V, V_{GS} = 0$ f = 1.0KHz			3.0	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 10V, V_{GS} = 0$ f = 1.0MHz			1.5	pF

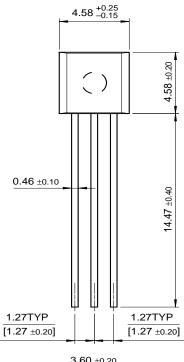
<sup>\*</sup> Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 1.0%

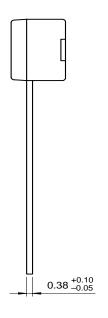
# Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

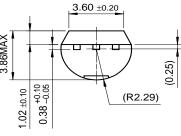
Symbol	Parameter	Max.	Units
$P_{D}$	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

# **Package Dimensions**

TO-92







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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
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